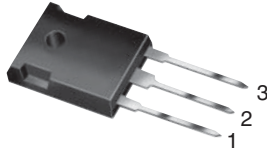
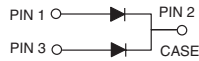


Dual High-Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.57\text{ V}$ at $I_F = 8\text{ A}$

TO-247AD (TO-3P)

FEATURES


- Trench MOS Schottky Technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Solder Dip 260 °C, 40 seconds
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, free-wheeling diodes, Oring diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade

Polarity: As marked

Mounting Torque: 10 in-lbs Maximum

MAJOR RATINGS AND CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	100 V
I_{FSM}	120 A
V_F at $I_F = 15\text{ A}$	0.65 V
T_j max.	150 °C

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V30100P	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100	V
Maximum average forward rectified (see Fig. 1)	$I_{F(AV)}$	30 15	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	120	A
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	at $I_R = 1.0\text{ mA}$ $T_j = 25\text{ }^\circ\text{C}$	$V_{(BR)}$	100 (minimum)	-	V
Instantaneous forward voltage ⁽¹⁾ per diode	at $I_F = 8\text{ A}$ $T_j = 25\text{ }^\circ\text{C}$ $I_F = 15\text{ A}$	V_F	0.64 0.78	- 0.85	V
	at $I_F = 8\text{ A}$ $T_j = 125\text{ }^\circ\text{C}$ $I_F = 15\text{ A}$		0.57 0.65	- 0.71	
Reverse current ⁽¹⁾ per diode	at $V_R = 70\text{ V}$ $T_j = 25\text{ }^\circ\text{C}$ $T_j = 125\text{ }^\circ\text{C}$	I_R	3.30 3.25	- -	μA mA
	at $V_R = 100\text{ V}$ $T_j = 25\text{ }^\circ\text{C}$ $T_j = 125\text{ }^\circ\text{C}$		13.7 7.2	300 20	μA mA

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V30100P	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	$^\circ\text{C/W}$

ORDERING INFORMATION				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
V30100P-E3/45	6.12	45	30/Tube	Tube

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

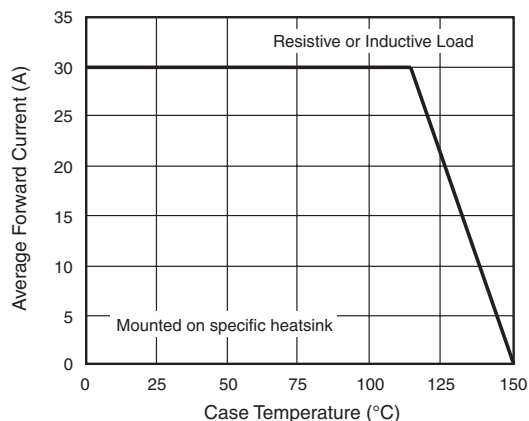


Figure 1. Forward Current Derating Curve

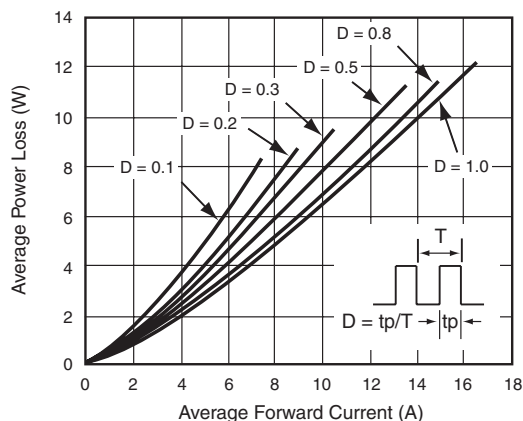


Figure 2. Forward Power Loss Characteristics Per Diode

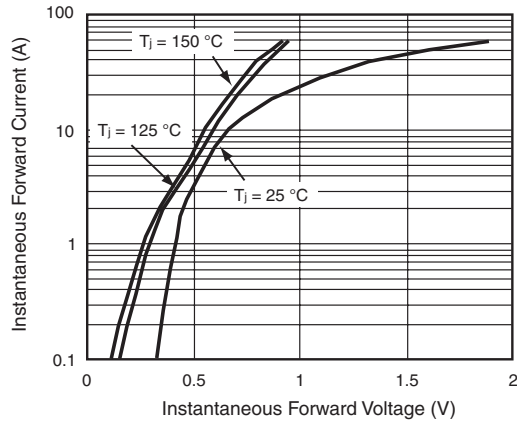


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

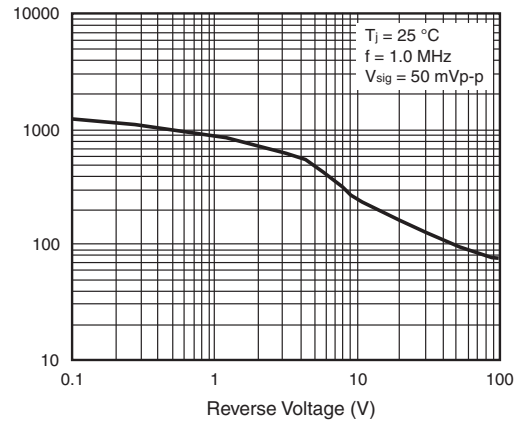


Figure 5. Typical Junction Capacitance Per Diode

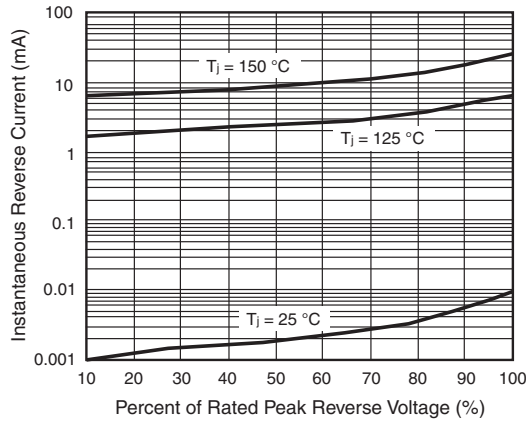


Figure 4. Typical Reverse Characteristics Per Diode

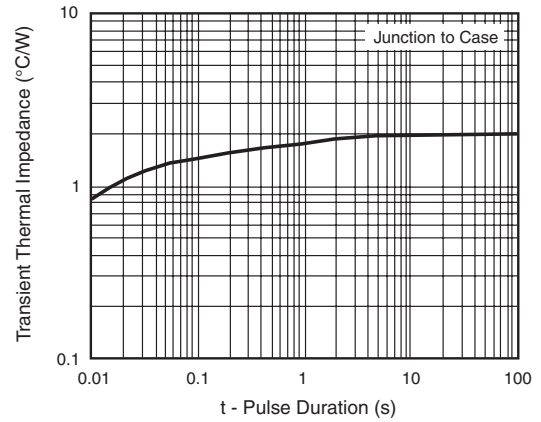
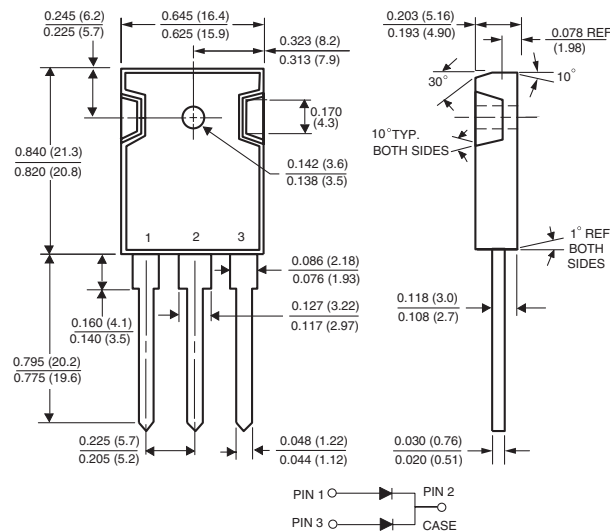


Figure 6. Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-247AD (TO-3P)




Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.